Ordering number: EN 5009

Thick Film Hybrid IC



Overview

The STK73904 incorporates on-chip all the power switching, amplifier, overcurrent protection and driver circuits required in a self-excitation type feedback control off-line switching regulator. As a result, it can be used in the design of switching power supplies with minimal number of external components. Furthermore, the adoption of MOSFET power switching elements supports a higher oscillator frequency than that possible with bipolar transistors. This allows smaller pulse transformers and capacitors to be used, making it possible to construct miniature power supply systems.

Applications

- CRT/CTV power supplies
- Office automation equipment power supplies

Features

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- Power MOSFET devices
- · Feedback control for high output voltage precision
- Driver circuit on-chip
- Overcurrent protection circuit on-chip
- Pin compatible with all other devices in the same series of devices with 110 to 280W power ratings
- Higher oscillator frequency allows the use of smaller pulse transformers
- IMST substrate acts as an electromagnetic shield, making low-noise designs possible

Package Dimensions

unit: mm

4121



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STK73904

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$, $Tc = 25^{\circ}C$ unless otherwise specified

Parameter	Symbol	Conditions	Ratings	Unit	
Operating substrate temperature	Tc max	Recommended value is 105°C.	115	°C	
AC input voltage	V _{AC}	Specified test circuit	140	Vrms	
Operating temperature	Topr		-10 to +85		
Storage temperature	Tstg		-30 to +115	°C	
Maximum output power	Wo max	Specified test circuit, $V_0 = 115V$	210	w	
[TR1]	• · · · · · · · · · · · · · · · · · · ·			· · · · · · · · · · · · · · · · · · ·	
Drain current	Ι _D	Refer to ASO characteristics for	12	A	
Pulse drain current	I _{D(pulse)}	overcurrent condition.	48	A	
Drain reverse current	L ^{DR}		12	A	
Gate-source voltage	V _{GSS}		±30	v	
Allowable power dissipation	PD		100	W	
Chip junction temperature	Tj max		150	0°C	
[ZD1]				··	
Allowable power dissipation	P _{ZD1}		500	Wm	
Chip junction temperature	Tj _(ZD1) max		125	°C	

Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Pin 4 input voltage	V ₄		±8 to ±24	V
Osciliator frequency	fosc		20 to 120	kHz

Operating Characteristics at $Ta = 25^{\circ}C$, $Tc = 25^{\circ}C$ unless otherwise specified, specified test circuit

Parameter Symbol		Conditions	min	typ	max	Unit	
[TR1]							
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10mA, V _{GS} = 0V	500	-	_	V	
Gate-source cutoff voltage	V _{GS(oll)}	$I_{\rm D} = 1 {\rm mA}, V_{\rm DS} = 10 {\rm V}$ 2		-	3.0	v	
ON resistance	R _{DS(on)}	R _{DS(on)}	$l_{\rm D} = 6 {\rm A}, {\rm V}_{\rm GS} = 10 {\rm V}$	_	0.45	0.7	Ω
Input capacitance	Ciss	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz		1450	_	pF	
[ZD1]		, <u>, , , , , , , , , , , , , , , , , , </u>	.,				
Zener vollage	Vz	$I_Z = 5 m A$	23.7	-	26.3	٧	

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STK73904

Block Diagram



The back surface of the IC is not an insulator, and is effectively at pin 2 potential.

Pin Functions

Pin No.	Function						
· 1	Amplifier circuit control						
2	Ground						
3	TR1 gale						
4	Drive voltage input						
5	Starting voltage input						
6	OCP setting level input						
7	OCP input-voltage dependency detection input						
8							
9	TR1 source						
11							
12	TR1 drain						

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Circuit Function Diagram







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Pulse Transformer Specifications



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STK73904

Series Organization

These devices form a series with varying output power ratings.

	Maximum ratings				Operating characteristics			
Type No.	V _{DSS} {V]	Tstg [°C]	Tc max [°C]	Tj max [°C]	ι _ρ [A]	input voltage [V]	Output power [W]	ON resistance [Ω]
STK73902		l			6.0		110	1.4
STK73903	1				10.0	05 4- 100	180	0.6
STK73904	500	90 to +115		+150	12.0	85 to 132	210	0.55
STK73905					15.0		280	0.3
STK73906					3.0		110	5.0
STK73907	900				5.0		180	3.0
STK73908		900			6.0		210	2.0
STK73909					8.0		280	1.2

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